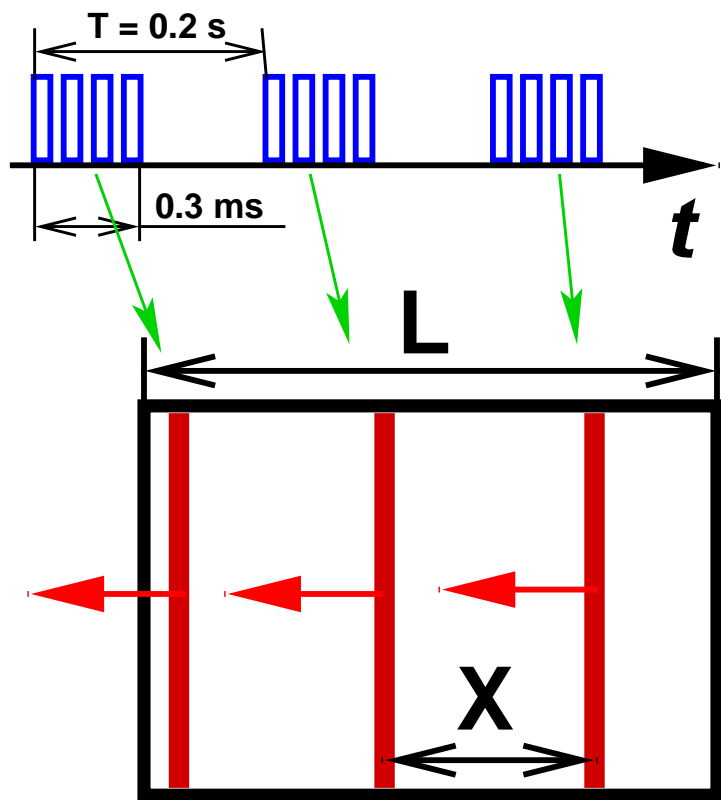


Triple-GEM performance in He-based mixtures

BINP group in TESLA TPC collaboration:

A. Bondar, A. Buzulutskov, L. Shekhtman , A. Vasiljev



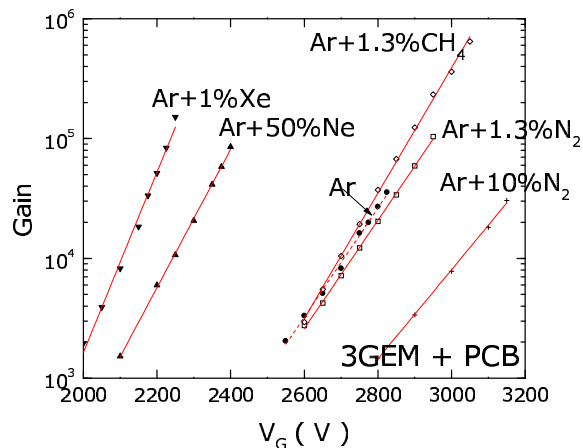
$$Q = \frac{L}{E K_0} i_{prim} \times Gain \times F$$

for micropattern detectors
feedback is proportional to drift
field, so Q does not depend on
drift field!

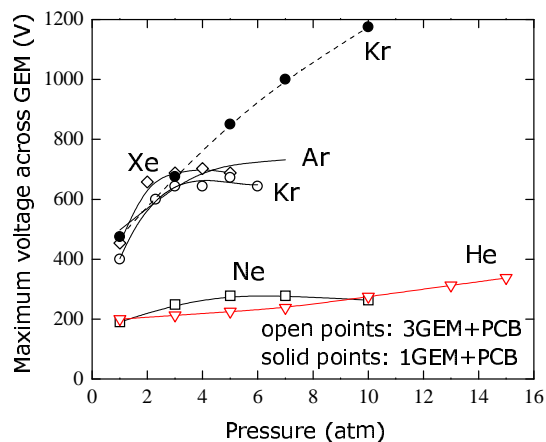
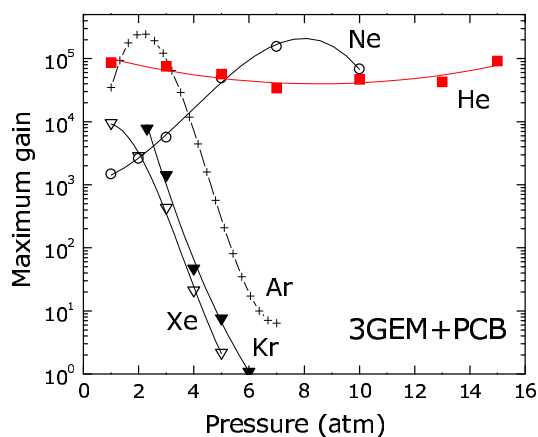
gas	He		Ne		Ar	
ion	He^+	He_2^+	Ne^+	Ne_2^+	Ar^+	Ar_2^+
$K_0, \frac{cm^2}{V \times s}$	10.4	16.7	4.1	6.5	1.5	1.86

GEM operation in noble gases: previous results

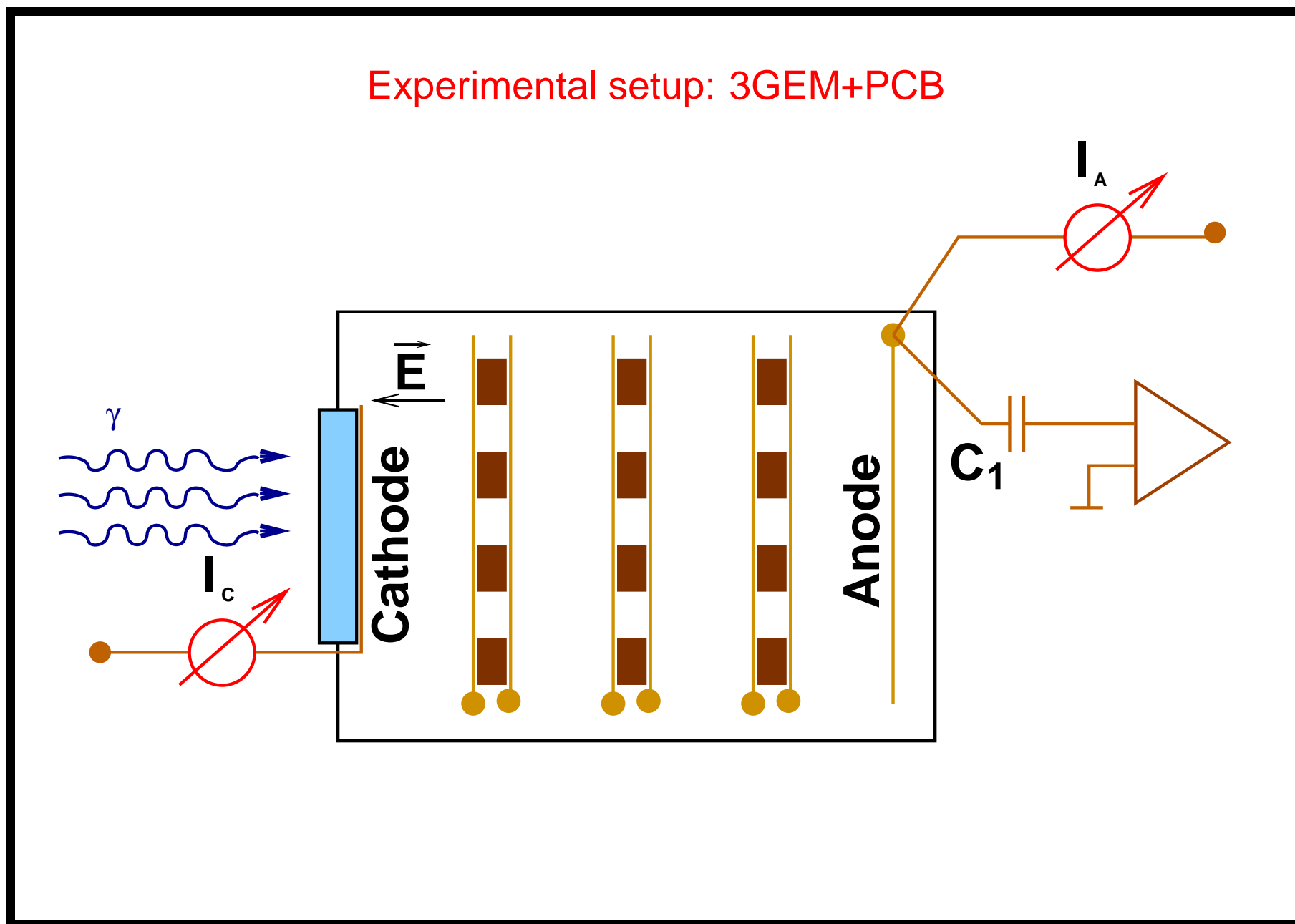
Weismann Institute & Budker Institute & CERN: NIM A 443(2000)164



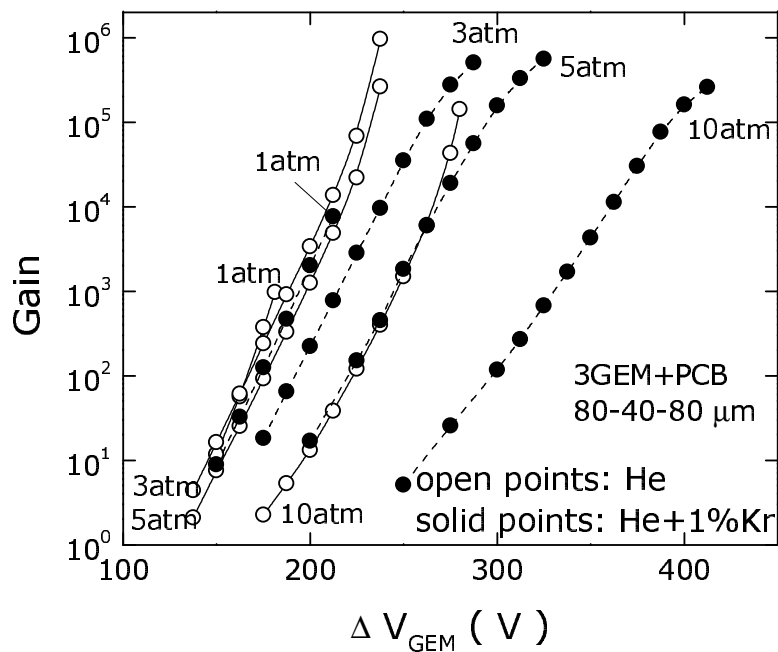
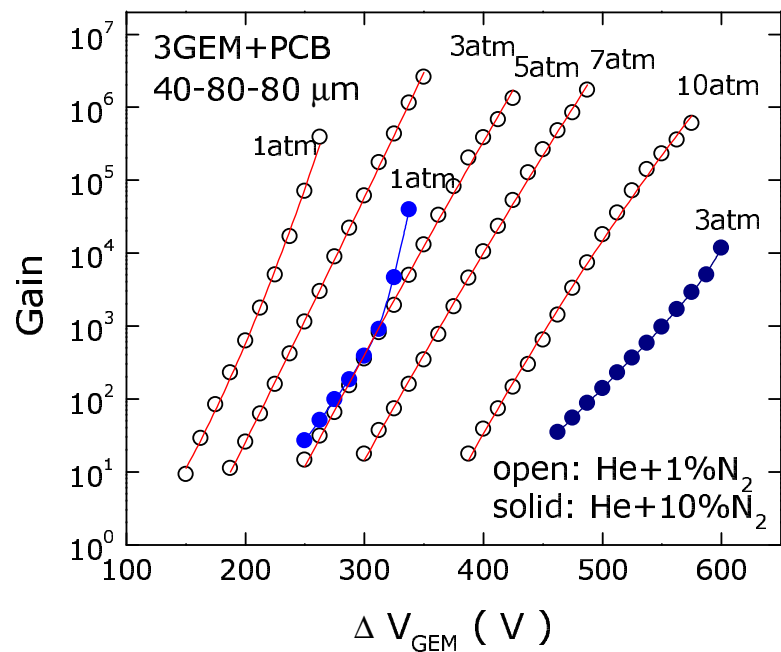
Budker Institute: NIM A 493(2002)18; 494(2002)148; 513 (2003) 256



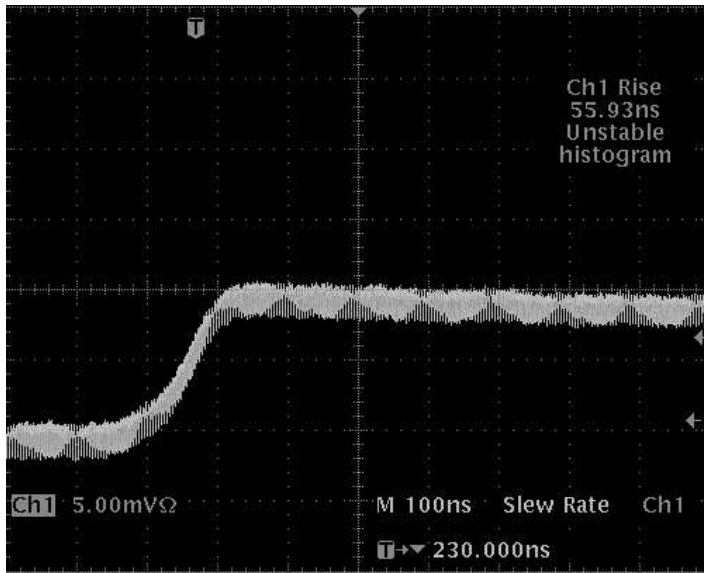
Experimental setup: 3GEM+PCB



GEM operation in *He*-based mixtures



*N*₂ addition to make signal faster

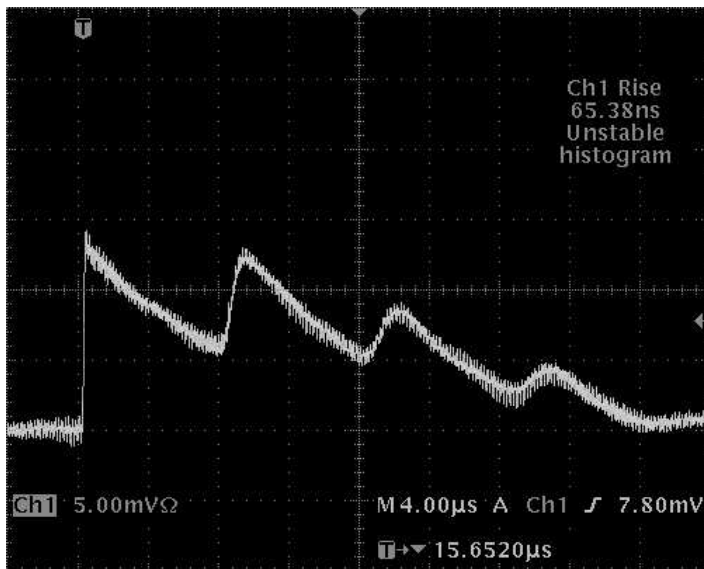


100 ns/div

$\text{He} + 10\% \text{N}_2, 1 \text{Atm}$

$\text{Gain} \sim 4500$

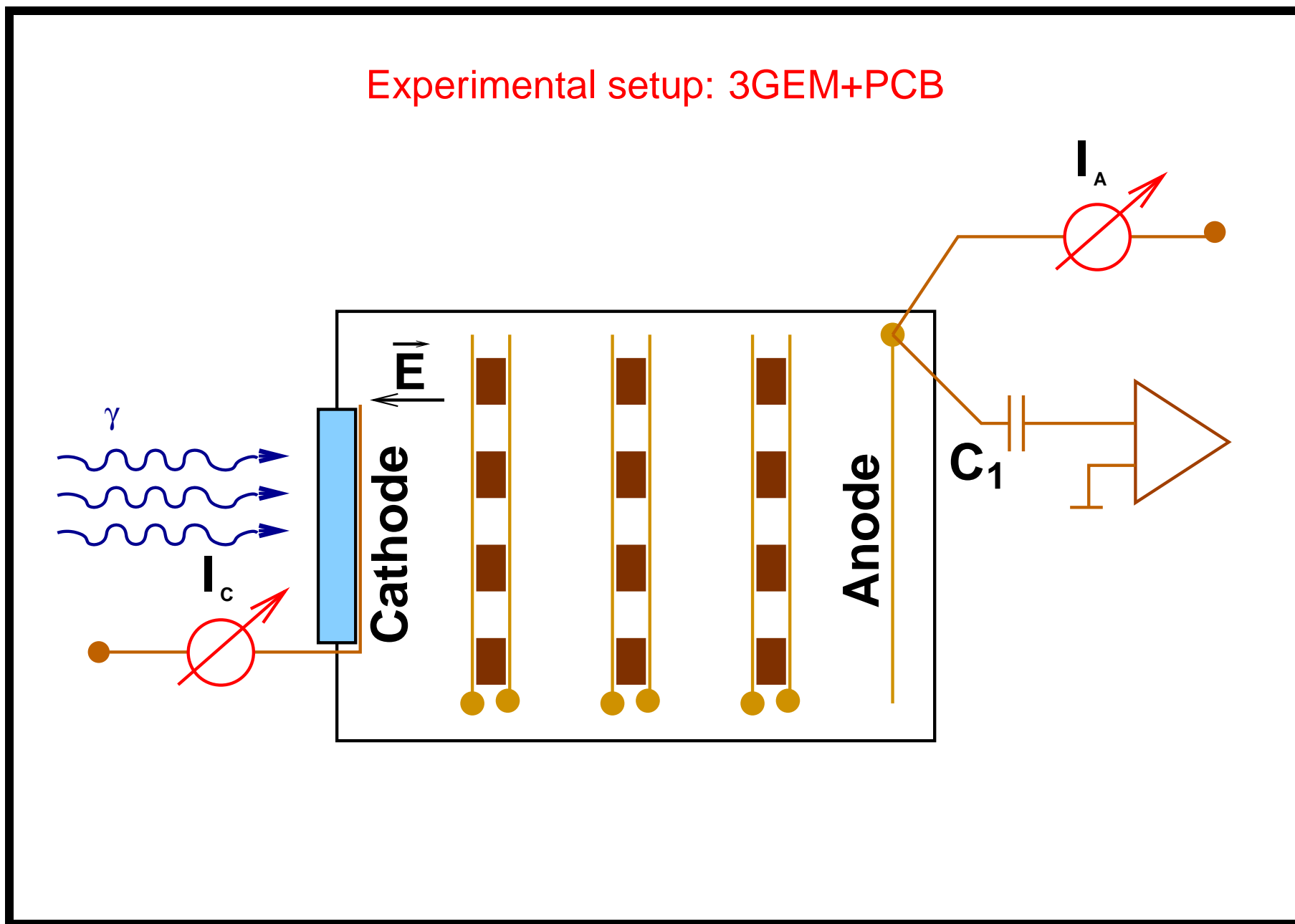
charge-sensitive amplifier



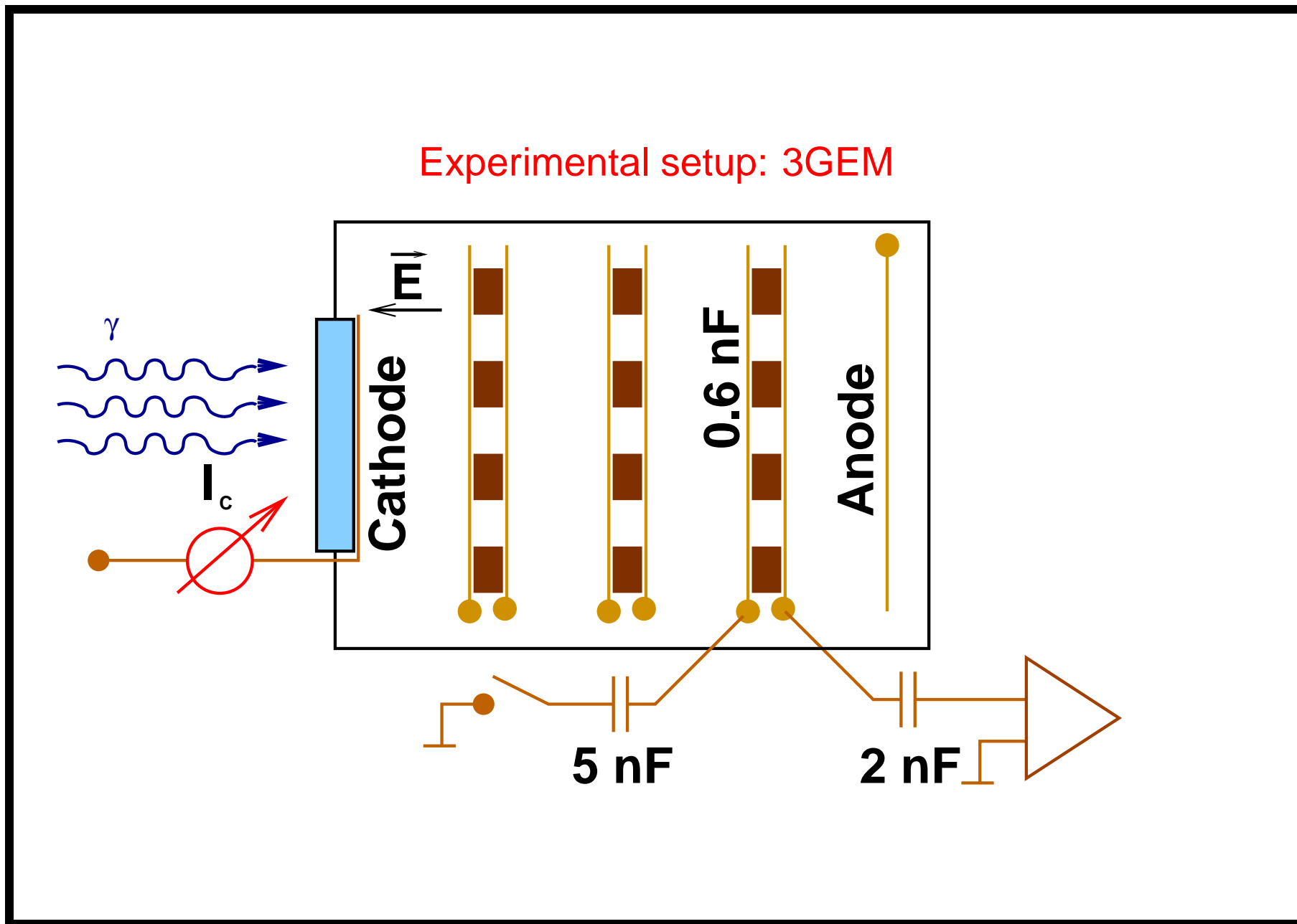
$4 \mu\text{s/div}$

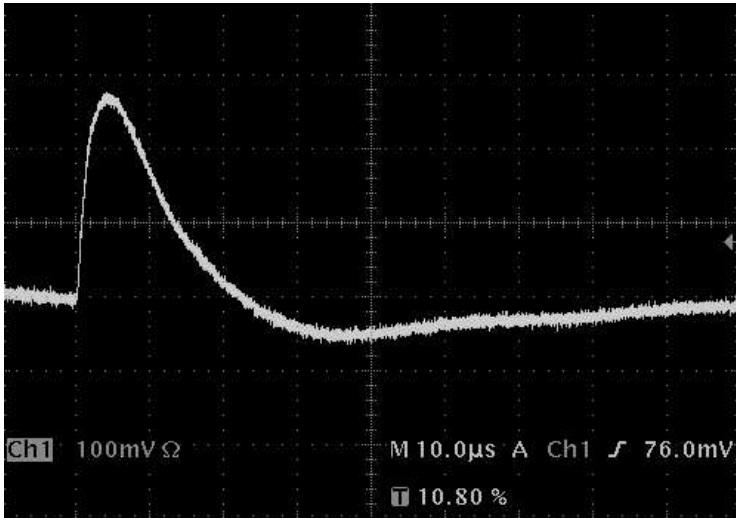
$$K_0 = 14.5 \frac{\text{cm}^2}{\text{V} \times \text{s}}$$

Experimental setup: 3GEM+PCB



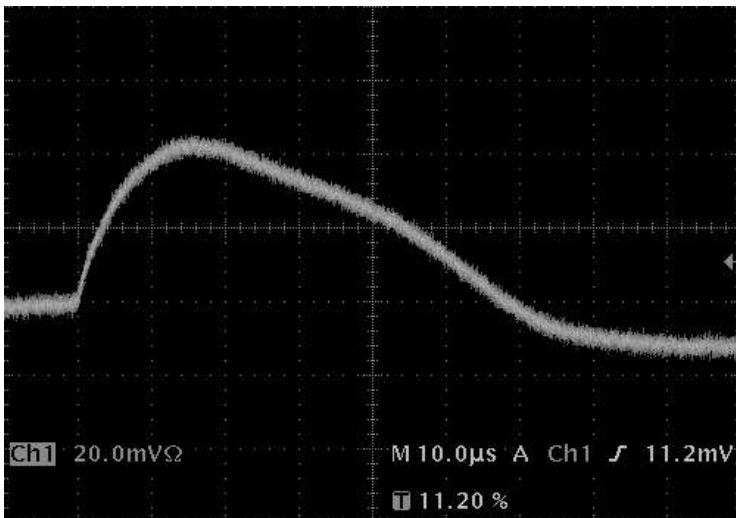
Experimental setup: 3GEM



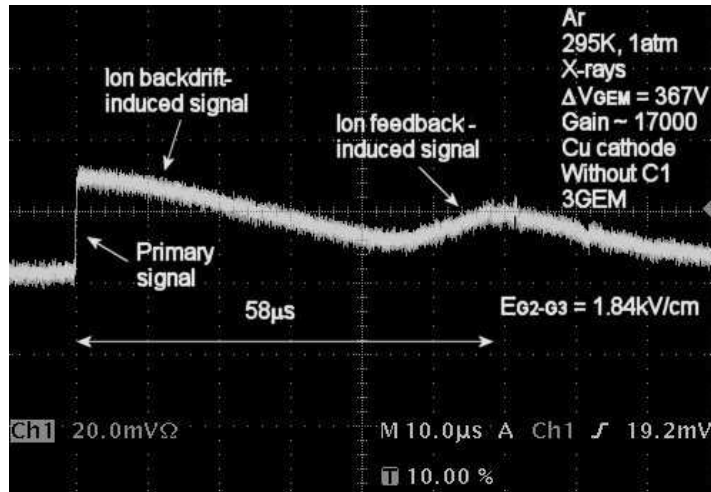


with capacitor
100 mV/div
primary (electron) signal

He, $Gain \sim 30000$



without capacitor
20 mV/div
ion-backdrift induced signal

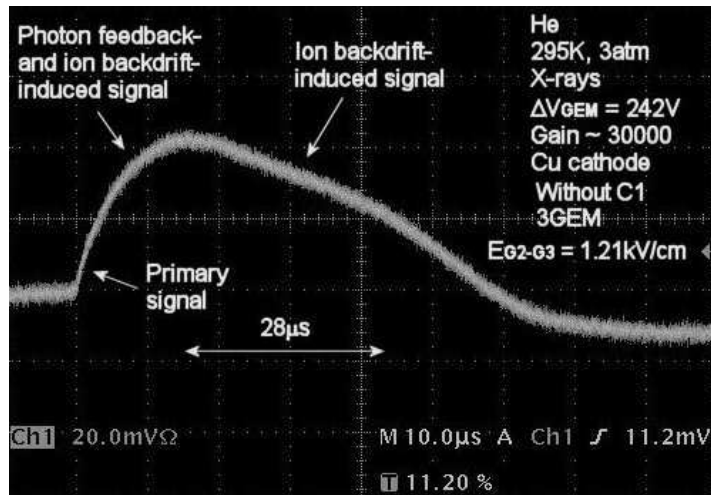


Ar, $P = 1Atm$,

Gain ~ 17000 ,

$$K_0 = 1.74 \frac{cm^2}{V \times s}$$

(Compare to 1.50 and 1.86 $\frac{cm^2}{V \times s}$ for Ar^+ and Ar_2^+ , respectively)



He, $P = 3Atm$,

Gain ~ 30000 ,

$$K_0 = 16.4 \frac{cm^2}{V \times s}$$

(Compare to 10.4 and 16.7 $\frac{cm^2}{V \times s}$ for He^+ and He_2^+ , respectively)

Summary

- One can reduce space-charge in TPC using a mixture with higher ion mobility.
- This mixture could be pure He or He-based plus some non-ageing components or else pure Ne or Ne-based. GEM works well whatever the case.
- Ion mobility of given mixture could be estimated with multi-GEM structure.